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PATENT
Attorney's Doc. No. 9898-321
Client Ref. No. SS-18146-US

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent No.: US 6,897,106 B2
Inventor: Park et al.
Issued: May 24, 2005

For: CAPACITOR OF SEMICONDUCTOR MEMORY DEVICE THAT HAS
COMPOSITE $\text{Al}_2\text{O}_3/\text{HfO}_2$ DIELECTRIC LAYER AND METHOD OF
MANUFACTURING THE SAME

Ser. No.: 10/713,577 Filed: November 12, 2003
Group Art Unit: 2818 Examiner: David Nhu

REQUEST FOR CERTIFICATE OF CORRECTION

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Certificate
OCT 16 2006
of Correction

Upon comparison of the above-identified original Letters Patent with applicant's copy of the application therefore, the following error in the original Letters Patent has been noted:

At column 7, line 10, please replace " $\text{Al}_2\text{O}_3\text{HfO}_2$ " with -- $\text{Al}_2\text{O}_3/\text{HfO}_2$ --
At column 7, line 44, please replace "FIG. 1" with --FIG. 10--
At column 8, line 12, please replace "thick. Al_2O_3 " --thick Al_2O_3 --
At column 9, line 11, please replace "thickness begin smaller" with --thickness being smaller--
At column 10, line 14, please replace "Pt, an a" with --Pt, and a--

Applicant respectfully requests that a Certificate of Correction calling attention to the above error be issued pursuant to Rule 322 of the Patent Office and Title 35, United States Code, Section 254. Two copies of a Certificate of Correction form are enclosed.

Respectfully submitted,

MARGER JOHNSON & McCOLLOM, P.C.

Hosoon Lee
56,737

OCT 17 2006

MARGER JOHNSON & McCOLLOM, P.C.
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22313-1450

Date: October 7, 2006



Kelly Andrews

OCT 17 2006



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TRANSMITTAL LETTER

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Enclosed for filing are the following:

- ☒ Request for Certificate of Correction
- ☒ Certificate of Correction Form PTO 1050 (in duplicate)
- ☒ Return postcard
- ☒ Any deficiency or overpayment should be charged or credited to deposit account number 13-1703.

Respectfully submitted,

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Date: October 9, 2006

Kelly Andrews

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(Also Form PTO-1050)

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MAILING ADDRESS OF SENDER:

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